

<<半导体物理电子学>>

图书基本信息

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内容概要

本书全面介绍了半导体物理的基本内容，这些内容是理解半导体的物理性质和光电器件制备原理的基础。

本书系统性强，合理地安排了物理原理，表征法以及半导体材料和器件的应用等内容，兼顾了物理学家、材料学家和设备工程师的需求。

本书反映了半导体技术在过去十年的进步，包括许多新出现并已进入市场的半导体器件。

本书适合于电子工程，材料科学，物理和化学工程的研究生，也可供半导体工业的过程工程师和设备工程师参考。

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编辑推荐

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